

# GP1S27

## Subminiature Photointerrupter

### ■ Features

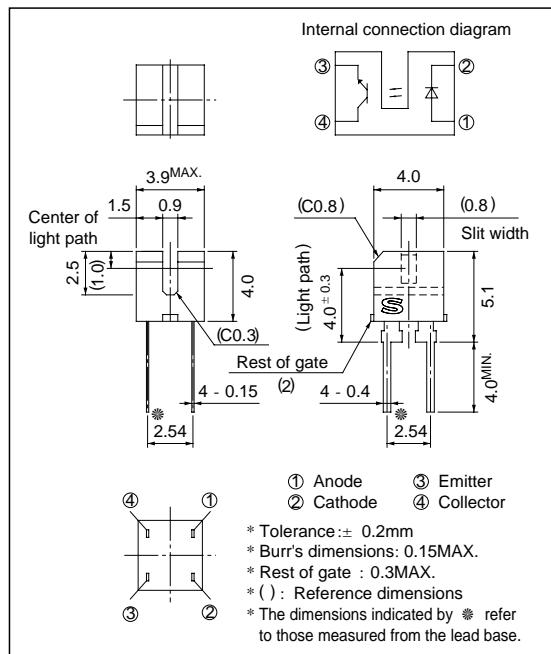
1. Ultra-compact
2. PWB mounting type package
3. Current transfer ratio  
(CTR : MIN. 4.3% )

### ■ Applications

1. Cameras
2. Floppy disk drives

### ■ Outline Dimensions

(Unit : mm)

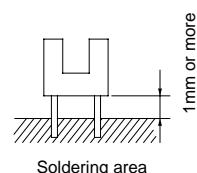


### ■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	50	mA
	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	P	75	mW
Output	Collector-emitter voltage	V <sub>CEO</sub>	35	V
	Emitter-collector voltage	V <sub>ECO</sub>	6	V
	Collector current	I <sub>C</sub>	20	mA
	Collector power dissipation	P <sub>C</sub>	75	mW
Total power dissipation		P <sub>tot</sub>	100	mW
Operating temperature		T <sub>opr</sub>	- 25 to + 85	°C
Storage temperature		T <sub>stg</sub>	- 40 to + 100	°C
* <sup>1</sup> Soldering temperature		T <sub>sol</sub>	260	°C

\*1 For 5 seconds

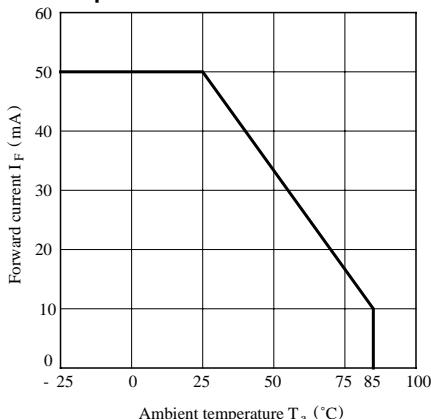


## ■ Electro-optical Characteristics

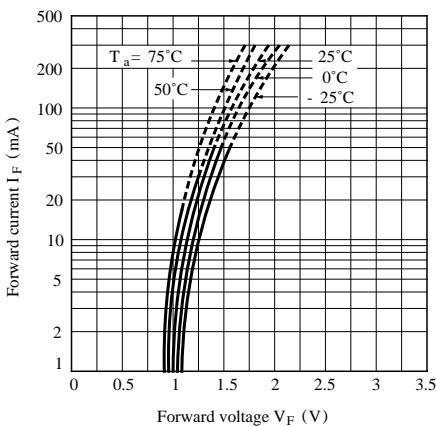
(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 20mA	-	1.2	1.4	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 3V	-	-	10	μA
Output	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> = 20V	-	-	1 x 10 <sup>-7</sup>	A
Transfer characteristics	Collector Current	I <sub>C</sub>	I <sub>F</sub> = 1.5mA, V <sub>CE</sub> = 5V	65	-	200	μA
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> = 3mA, I <sub>C</sub> = 30 μA	-	-	0.4	V
	Response time	t <sub>r</sub>	V <sub>CE</sub> = 5V, R <sub>L</sub> = 1kΩ	-	50	150	μs
		t <sub>f</sub>	I <sub>C</sub> = 100 μA	-	50	150	μs

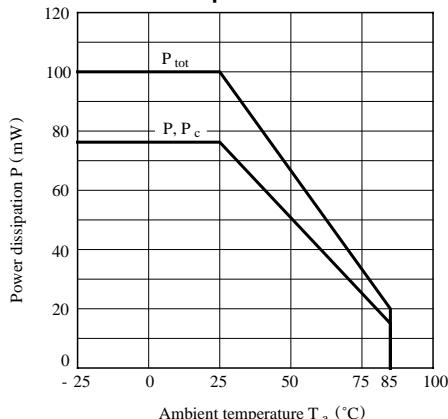
**Fig. 1 Forward Current vs. Ambient Temperature**



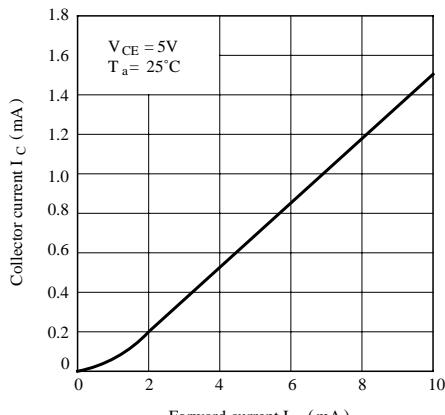
**Fig. 3 Forward Current vs. Forward Voltage**



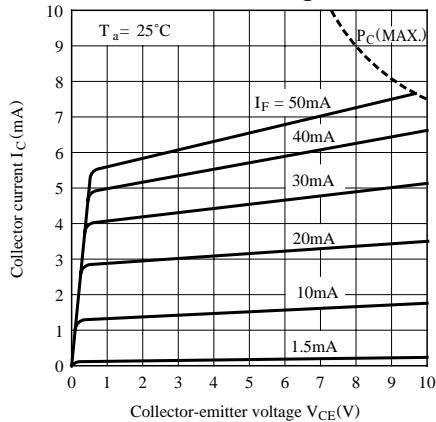
**Fig. 2 Power Dissipation vs. Ambient Temperature**



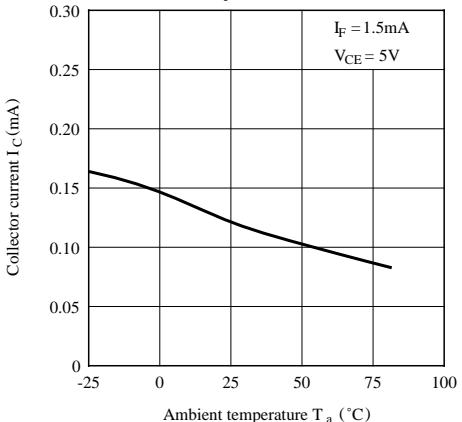
**Fig. 4 Collector Current vs. Forward Current**



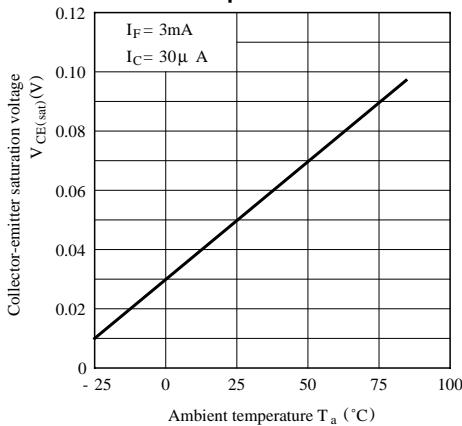
**Fig. 5 Collector Current vs.  
Collector-emitter Voltage**



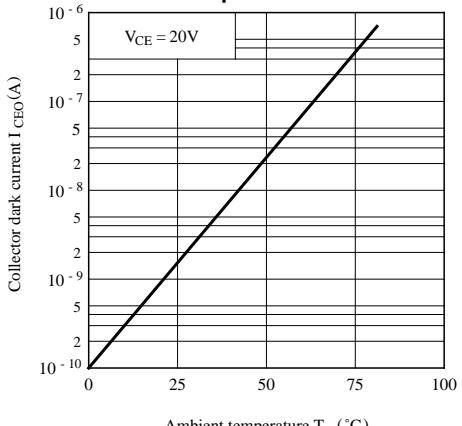
**Fig. 6 Collector Current vs.  
Ambient Temperature**



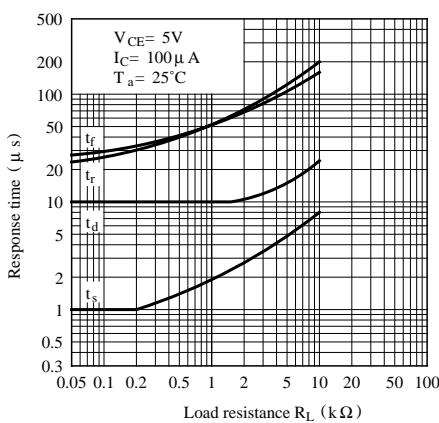
**Fig. 7 Collector-emitter Saturation Voltage vs.  
Ambient Temperature**



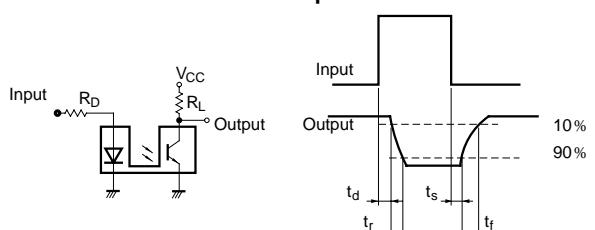
**Fig. 8 Collector Dark Current vs.  
Ambient Temperature**



**Fig. 9 Response Time vs. Load Resistance**



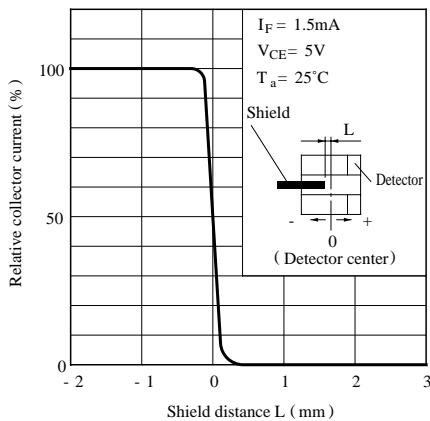
**Test Circuit for Response Time**



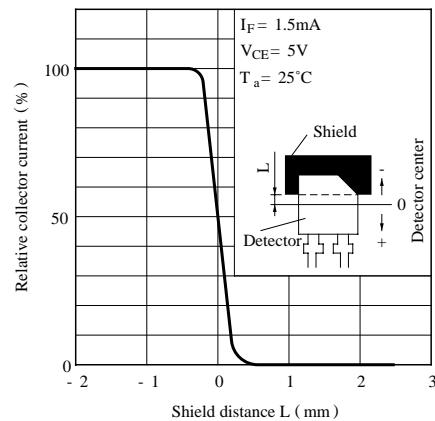
10%      90%

t<sub>d</sub>      t<sub>r</sub>      t<sub>s</sub>      t<sub>f</sub>

**Fig.10 Relative Collector Current vs.  
Shield Distance (1)**



**Fig.11 Relative Collector Current vs.  
Shield Distance (2)**



## ■ Precautions for Use

- (1) Please refrain from soldering under preheating and refrain from soldering by reflow.
- (2) As for other general cautions, refer to the chapter "Precautions for Use".